TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH367FK,TC7MH368FK

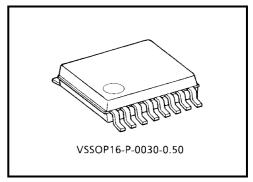
HEX Bus Buffer

TC7MH367FK Non-Inverted, 3-State Outputs TC7MH368FK Inverted, 3-State Outputs

The TC7MH367FK and TC7MH368FK are advanced high speed CMOS HEX bus buffers fabricated with silicon gate $\rm C^2MOS$ technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input $(\overline{G}1)$, and the other two buffers are controlled by another enable input $(\overline{G}2)$. The outputs of each buffer group are enabled when $\overline{G}1$ and/or $\overline{G}2$ inputs are held low; if held high, these outputs are in a high impedance state.



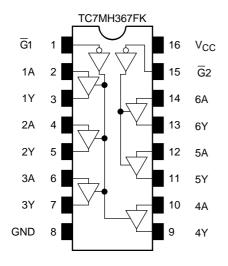
Weight: 0.02 g (typ.)

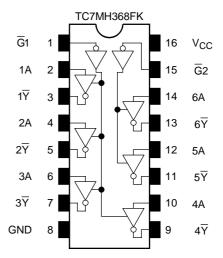
The TC7MH367FK is a non-inverting output type, while the TC7MH368FK is an inverting output type. An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

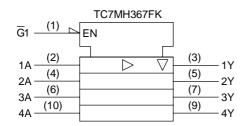
- High speed: $t_{pd} = 3.8 \text{ ns (typ.)} (V_{CC} = 5 \text{ V})$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- · Power down protection is provided on all inputs.
- Balanced propagation delays: $t_pLH \approx t_pHL$
- Wide operating voltage range: $V_{CC (opr)} = 2 \sim 5.5 \text{ V}$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS367/368

Pin Assignment (top view)

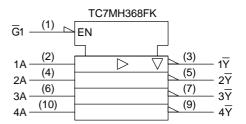


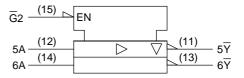


IEC Logic Symbol









Truth Table

Inp	uts	Outputs				
G	Α	Y (367)	Y (368)			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

- X: Don't care
- Z: High impedance



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vout	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~V _{CC}	V	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	$0 \sim 100 \; (V_{CC} = 3.3 \pm 0.3 \; V)$	ns/V	
Input noe and rail time	ui/uv	$0 \sim 20 \ (V_{CC} = 5 \pm 0.5 \ V)$	113/V	

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Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Condition		Cumbal	Cumbal Test Condition			Ta = 25°C)	Ta = -40~85°C		Unit
		V _{CC} (V)	Min	Тур.	Max	Min	Max				
					2.0	1.50	_	_	1.50	_	
High level Input voltage	High level	V _{IH}	_		3.0~5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7	-	V
input voltage			_		2.0		_	0.50	_	0.50	
	Low level	V_{IL}			3.0~5.5		_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times 0.3 \end{array}$	
					2.0	1.9	2.0		1.9	_	
		Vон	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \ \mu A$	3.0	2.9	3.0		2.9		
Output voltage	High level				4.5	4.4	4.5	_	4.4	_	
				$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_	
				$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_	V
	Low level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0	0.1		0.1	
					3.0	_	0	0.1	—	0.1	
					4.5	_	0	0.1	_	0.1	
				$I_{OL} = 4 \text{ mA}$	3.0	_	_	0.36	_	0.44	
				$I_{OL} = 8 \text{ mA}$	4.5	_	_	0.36	_	0.44	
3-state output off	-state current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_		±0.25		±2.50	μА
Input leakage cu	rrent	I _{IN}	V _{IN} = 5.5 V or GND		0~5.5	_	_	±0.1	_	±1.0	μА
Quiescent supply	/ current	Icc	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	_	40.0	μΑ



AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol Test Condition				Ta = 25°C			Ta = -40~85°C		Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Offic
			3.3 ± 0.3	15	_	5.9	8.3	1.0	10.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3	50	_	8.4	11.8	1.0	13.5	ns
(TC7MH367)	t _{pHL}	_	5.0 ± 0.5	15	_	4.1	5.9	1.0	7.0	113
			3.0 ± 0.3	50	_	5.6	7.9	1.0	9.0	
			3.3 ± 0.3	15	_	5.3	7.5	1.0	9.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3	50	_	7.8	11.0	1.0	12.5	ne
(TC7MH368)	t _{pHL}	_	5.0 ± 0.5	15	_	3.8	5.5	1.0	6.5	ns
				50	_	5.3	7.5	1.0	8.5	
	^t pZL I ^t pZH	R _L = 1 kΩ	3.3 ± 0.3 · 5.0 ± 0.5 ·	15	_	6.8	10.5	1.0	12.5	- ns
2 state output enable time				50	_	9.3	14.0	1.0	16.0	
3-state output enable time				15	_	4.8	7.2	1.0	8.5	
				50	_	6.3	9.2	1.0	10.5	
3-state output disable time	t _{pLZ}	$R_{I} = 1 k\Omega$	3.3 ± 0.3	50		9.9	13.6	1.0	15.5	ns
5-State output disable time	t _{pHZ}	NL - 1 K22	5.0 ± 0.5	50	_	6.3	9.2	1.0	10.5	115
Output to output skew	t _{osLH}	(Note1)	3.3 ± 0.3	50	_	_	1.5	_	1.5	ns
Output to output skew	t _{osHL}	(Note1)	5.0 ± 0.5	50			1.0	_	1.0	113
Input capacitance	C _{IN}	_	_		_	4	10	_	10	pF
Output capacitance	C _{OUT}	_		_	6		_	_	pF	
Power dissipation capacitance	C _{PD}			(Note2)	_	19		_	_	pF

Note1: Parameter guaranteed by design.

 $t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \, t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|$

Note2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

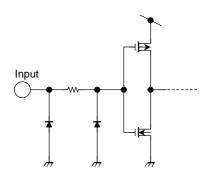
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 (per bit)$



Noise Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

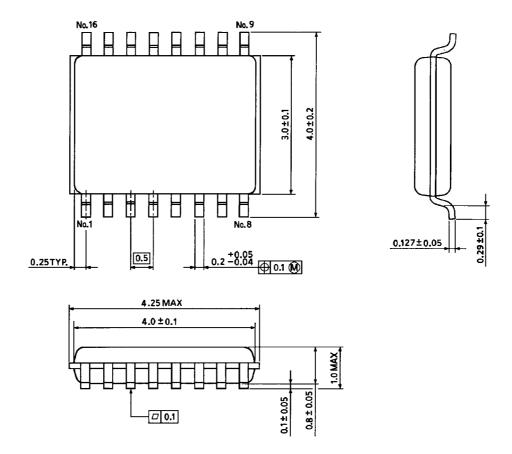
Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
Granacieristics	Symbol	rest Condition	V _{CC} (V)	Тур.	Limit	Oill
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dymnamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage V_{IH}	V_{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage $V_{\rm IL}$	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

Input Equivalent Circuit



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Package Dimensions



Weight: 0.02 g (typ.)

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000707EBA

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